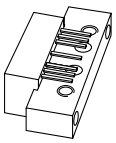


BGY585A

550 MHz, 18.2 dB gain push-pull amplifier

Rev. 05 — 24 January 2005 Product data sheet

1. Product profile

1.1 General description

Hybrid amplifier module for CATV systems operating over a frequency range of 40 MHz to 550 MHz at a voltage supply of 24 V (DC). Intended for use as a final amplifier.

1.2 Features

- Excellent linearity
- Extremely low noise
- Silicon nitride passivation
- Rugged construction
- Optimal reliability ensured by TiPtAu metallized crystals

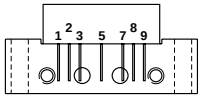
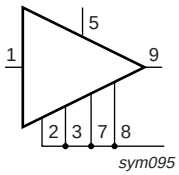
1.3 Quick reference data

Table 1: Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
G_p	power gain	f = 50 MHz	17.7	-	18.7	dB
		f = 550 MHz	18.8	-	20	dB
I_{tot}	total current consumption (DC)	V_B = 24 V	-	220	240	mA

2. Pinning information

Table 2: Pinning

Pin	Description	Simplified outline	Symbol
1	input	 Side view	 sym095
2	common		
3	common		
5	$+V_B$		
7	common		
8	common		
9	output		

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3. Ordering information

Table 3: Ordering information

Type number	Package		
	Name	Description	Version
BGY585A	-	rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 × 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads	SOT115J

4. Limiting values

Table 4: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_i	RF input voltage		-	65	dBmV
T_{stg}	storage temperature		–40	+100	°C
T_{case}	case operating temperature		–20	+100	°C

5. Characteristics

Table 5: Characteristics

T_{case} = 30 °C; Z_S = Z_L = 75 Ω.

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Bandwidth 40 MHz to 550 MHz							
G_p	power gain	f = 50 MHz		17.7	-	18.7	dB
		f = 550 MHz		18.8	-	20	dB
SL	slope cable equivalent	f = 40 MHz to 550 MHz		0.5	-	2	dB
FL	flatness of frequency response	f = 40 MHz to 550 MHz		-	-	±0.2	dB
s_{11}	input return losses	f = 40 MHz to 80 MHz		20	-	-	dB
		f = 80 MHz to 160 MHz		19	-	-	dB
		f = 160 MHz to 550 MHz		18	-	-	dB
s_{22}	output return losses	f = 40 MHz to 80 MHz		20	-	-	dB
		f = 80 MHz to 160 MHz		19	-	-	dB
		f = 160 MHz to 550 MHz		18	-	-	dB
CTB	composite triple beat	77 channels flat; V_o = 44 dBmV; measured at 547.25 MHz		-	-	–59	dB
X_{mod}	cross modulation	77 channels flat; V_o = 44 dBmV; measured at 55.25 MHz		-	-	–62	dB
CSO	composite second order distortion	77 channels flat; V_o = 44 dBmV; measured at 548.5 MHz		-	-	–59	dB
d_2	second order distortion		[1]	-	-	–72	dB
V_o	output voltage	d_{im} = –60 dB	[2]	61.5	-	-	dBmV
F	noise figure	f = 550 MHz		-	-	8	dB
I_{tot}	total current consumption (DC)	V_B = 24 V	[3]	-	220	240	mA

Table 5: Characteristics *...continued*

T_{case} = 30 °C; Z_S = Z_L = 75 Ω.

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Bandwidth 40 MHz to 450 MHz							
G_p	power gain	f = 50 MHz		17.7	-	18.7	dB
		f = 450 MHz		18.6	-	19.8	dB
SL	slope cable equivalent	f = 40 MHz to 450 MHz		0.5	-	1.8	dB
FL	flatness of frequency response	f = 40 MHz to 450 MHz		-	-	±0.2	dB
s_{11}	input return losses	f = 40 MHz to 80 MHz		20	-	-	dB
		f = 80 MHz to 160 MHz		19	-	-	dB
		f = 160 MHz to 450 MHz		18	-	-	dB
s_{22}	output return losses	f = 40 MHz to 80 MHz		20	-	-	dB
		f = 80 MHz to 160 MHz		19	-	-	dB
		f = 160 MHz to 450 MHz		18	-	-	dB
CTB	composite triple beat	60 channels flat; V_o = 46 dBmV; measured at 445.25 MHz		-	-	–61	dB
X_{mod}	cross modulation	60 channels flat; V_o = 46 dBmV; measured at 55.25 MHz		-	-	–61	dB
CSO	composite second order distortion	60 channels flat; V_o = 46 dBmV; measured at 446.5 MHz		-	-	–61	dB
d_2	second order distortion		[4]	-	-	–75	dB
V_o	output voltage	d_{im} = –60 dB	[5]	64	-	-	dBmV
F	noise figure	f = 450 MHz		-	-	7	dB
I_{tot}	total current consumption (DC)	V_B = 24 V	[3]	-	220	240	mA

[1] f_p = 55.25 MHz; V_p = 44 dBmV; f_q = 493.25 MHz; V_q = 44 dBmV; measured at $f_p + f_q$ = 548.5 MHz.

[2] Measured according to DIN45004B; f_p = 540.25 MHz; $V_p = V_o$; f_q = 547.25 MHz; $V_q = V_o$ –6 dB; f_r = 549.25 MHz; $V_r = V_o$ –6 dB; measured at $f_p + f_q - f_r$ = 538.25 MHz.

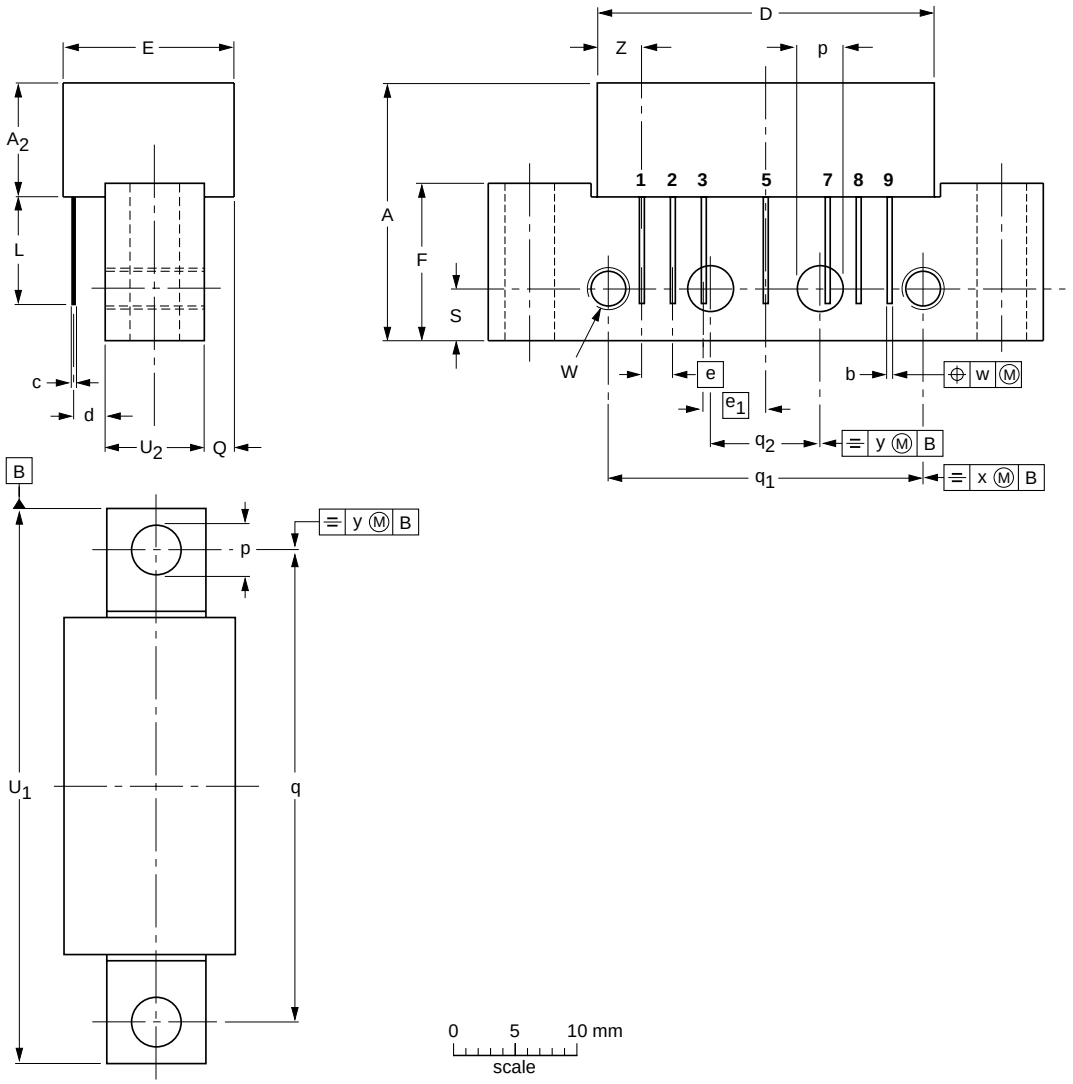
[3] The module normally operates at V_B = 24 V, but is able to withstand supply transients up to 30 V.

[4] f_p = 55.25 MHz; V_p = 46 dBmV; f_q = 391.25 MHz; V_q = 46 dBmV; measured at $f_p + f_q$ = 446.5 MHz.

[5] Measured according to DIN45004B; f_p = 440.25 MHz; $V_p = V_o$; f_q = 447.25 MHz; $V_q = V_o$ –6 dB; f_r = 449.25 MHz; $V_r = V_o$ –6 dB; measured at $f_p + f_q - f_r$ = 438.25 MHz.

6. Package outline

Rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads **SOT115J**



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A_2 max.	b	c	D max.	d max.	E max.	e	e_1	F	L min.	p	Q max.	q	q_1	q_2	S	U_1	U_2	W	w	x	y	Z max.
mm	20.8	9.1	0.51 0.38	0.25	27.2	2.54	13.75	2.54	5.08	12.7	8.8	4.15 3.85	2.4	38.1	25.4	10.2	4.2	44.75 44.25	8.2 7.8	6-32 UNC	0.25	0.7	0.1	3.8

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT115J						~~99-02-06~~ 04-02-04

Fig 1. Package outline SOT115J

7. Revision history

Table 6: Revision history

Document ID	Release date	Data sheet status	Change notice	Doc. number	Supersedes
BGY585A_5	20050124	Product data sheet	-	9397 750 14432	BGY585A_4
Modifications:	• The format of this data sheet has been redesigned to comply with the new presentation and information standard of Philips Semiconductors.				
BGY585A_4	20011018	Product specification	-	9397 750 08802	BGY585A_3
BGY585A_3	19990326	Product specification	-	9397 750 06341	BGY585A_2

8. Data sheet status

Level	Data sheet status [1]	Product status [2] [3]	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
III	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

[1] Please consult the most recently issued data sheet before initiating or completing a design.

[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

9. Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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12. Contents

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